

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	2	"6693021".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/22 17:42
L1	4	("5962915" "6270569").pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/22 17:42
S19	68	(akira near2 usui or haruo near2 sunakawa or akira near2 sakai or atsushi near2 yamaguchi).in. and (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/22 18:14
L3	86	(akira near2 usui or haruo near2 sunakawa or akira near2 sakai or atsushi near2 yamaguchi).in. and (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/22 18:14
S12 5	48	(kensaku near2 motoki or takuji near2 okahisa or naoki near2 matsumoto).in. and mask\$5 near15 (GaAs or gallium near2 arsenide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/22 18:15
S10 8	9	mask near10 pattern\$6 near10 pitch near10 direction near10 parallel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/22 18:15
S10 2	14	(elo or lateral near2 overgrow\$5) same pitch	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/22 18:15
L6	23	(elo or lateral near2 overgrow\$5) same pitch	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/22 18:21
L5	12	mask near10 pattern\$6 near10 pitch near10 direction near10 parallel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/22 18:22

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L4	51	(kensaku near2 motoki or takuji near2 okahisa or naoki near2 matsumoto).in. and mask\$5 near15 (GaAs or gallium near2 arsenide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/22 18:23
S50	348	(gan or gallium near2 nitride) near15 substrate near10 (cut\$5 or cleav\$6 or slic\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/22 18:29
S24	195	(stripe mask\$4 or pattern\$6) near15 direction and (gan or gallium near2 nitride) near10 epitax\$7 and (gaas or gallium near2 arsenide) near10 substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/22 18:29
L8	600	(gan or gallium near2 nitride) near15 substrate near10 (cut\$5 or cleav\$6 or slic\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/22 18:29
L7	324	(stripe mask\$4 or pattern\$6) near15 direction and (gan or gallium near2 nitride) near10 epitax\$7 and (gaas or gallium near2 arsenide) near10 substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/22 18:29